

HL6750MG

Visible High Power Laser Diode

ODE-208-021A (Z) Rev.1

Dec. 21, 2006

Description

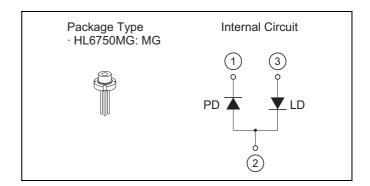
The HL6750MG is a 0.68 μ m band AlGaInP laser diode (LD) with a multi-quantum well (MQW) structure. It is suitable as a light source for various other types of optical equipment.

Features

High output power : 50 mW (CW)
 Small package : φ 5.6 mm
 Visible light output : λp = 685 nm Typ

• Single longitudinal mode

Low operating current: 75 mA typLow operating voltage: 2.3 V typ



Absolute Maximum Ratings

 $(T_C = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Optical output power	Po	55	mW
Laser diode reverse voltage	$V_{R(LD)}$	2	V
Photo diode reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	Topr	-10 to +70	°C
Storage temperature	Tstg	-40 to +85	°C

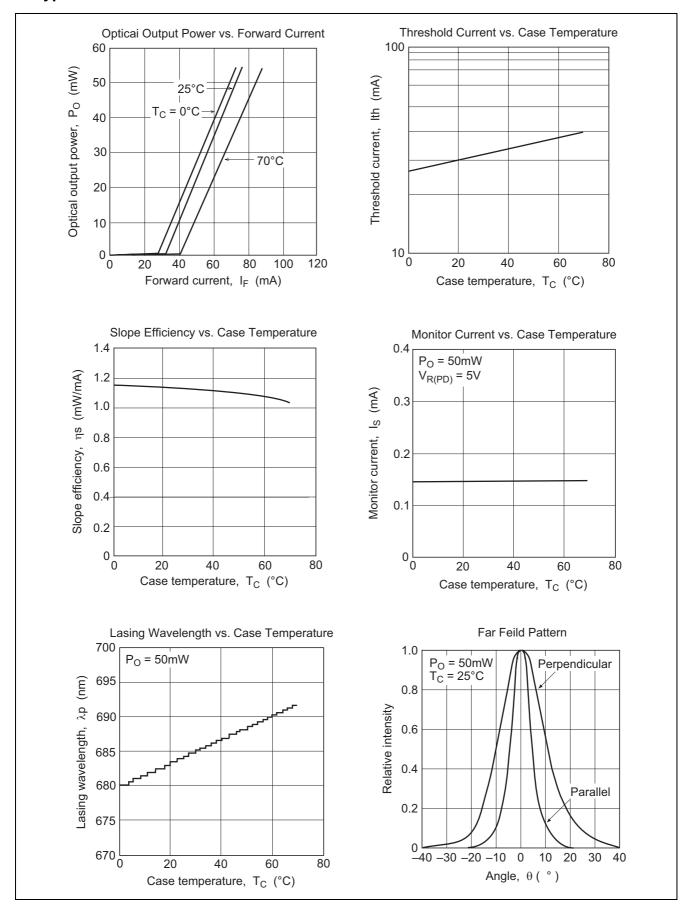
Optical and Electrical Characteristics

 $(T_C = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	Ith	_	30	60	mA	_
Operating voltage	V_{OP}	_	2.3	3.0	V	$P_O = 50 \text{ mW}$
Slope efficiency	ηѕ	0.8	1.1	1.4	mW/mA	$30(mW) / (I_{(40mW)} - I_{(10mW)})$
Operating current	I _{OP}	_	75	120	mA	$P_O = 50 \text{ mW}$
Beam divergence	θ//	7	9	12	0	$P_O = 50 \text{ mW}$
parallel to the junction						
Beam divergence	θΤ	18	21	25	0	$P_O = 50 \text{ mW}$
parpendicular to the junction						
Lasing wavelength	λр	675	685	695	nm	$P_O = 50 \text{ mW}$
Monitor current	Is	0.08	0.15	0.35	mA	$P_{O} = 50 \text{ mW}, V_{R(PD)} = 5 \text{ V}$
Asitgmatism	As	_	1	_	μm	$P_0 = 5 \text{ mW}, NA = 0.55$



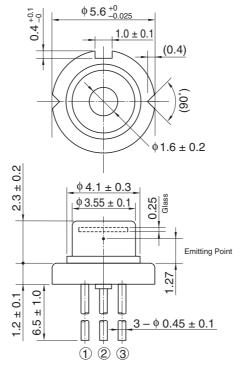
Typical Characteristic Curves

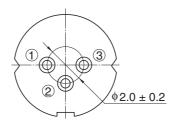


Package Dimensions

As of July, 2002 Unit: mm







OPJ Code	LD/MG
JEDEC	_
JEITA	_
Mass (reference value)	0.3 g

Cautions

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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.
 - When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
- 3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

Sales Offices



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